上海艾为电子技术股份有限公司
shanghai awinic technology co., ltd.

# Ultra-Low Noise Amplifier for Global Navigation Satellite Systems (GNSS)

## FEATURES

- Reduce RF environment Interference with patented Smart-Linearity-Technology (SLT);
- Ultra low current=7.8mA;
- Ultra low noise figure(NF)=0.75dB;
- High power gain=19dB;
- High input 1dB-compression point=-10.5dBm;
- GPS L1 requires only one input matching inductor;
- RF output internally matched to 50 ohm for GPS L1;
- Supply voltage: 1.5V to 3.3V;
- Operating frequencies: 1550~1615MHz; 1164~1215MHz;
- DFN 1.1 mmX0.7 mmX0.37 mm-6L package
- ±3kV HBM ESD protection (including RFIN and RFOUT pin)

## APPLICATIONS

- Smart Phones, Feature Phones;
- Tablet PCs;
- Personal Navigation Devices;
- Digital Still Cameras, Digital Video Cameras;
- RF Front End modules;
- Complete GPS chipset modules;
- Theft protection(laptop, ATM);

## GENERAL DESCRIPTION

The AW15145DNR is a Low Noise Amplifier designed for Global Navigation Satellite Systems (GNSS) as GPS, Beidou, GLONASS, Galileo and Compass. With on-chip DC blocking capacitors at RFIN and RFOUT, The AW15145DNR can be close to the antenna, requires only one external input matching inductor for GPS L1, and reduces assembly complexity and the PCB area, enabling a cost-effective solution.

The AW15145DNR with patented Smart Linearity Technology (SLT) achieves ultra-low noise figure, high linearity, high gain, over a wide range of supply voltages from 1.5V up to 3.3V. All these features make AW15145DNR an excellent choice for GNSS LNA as it improves sensitivity with low noise figure and high gain, provide better immunity against out-of-band jammer signals with high linearity, reduces filtering requirement of preceding stage and hence reduces the overall cost of the GNSS receiver.

The AW15145DNR is available in a small lead-free, RoHS-Compliant, DFN 1.1 mm X 0.7 mm X 0.37 mm-6L package.

# TYPICAL APPLICATION CIRCUIT
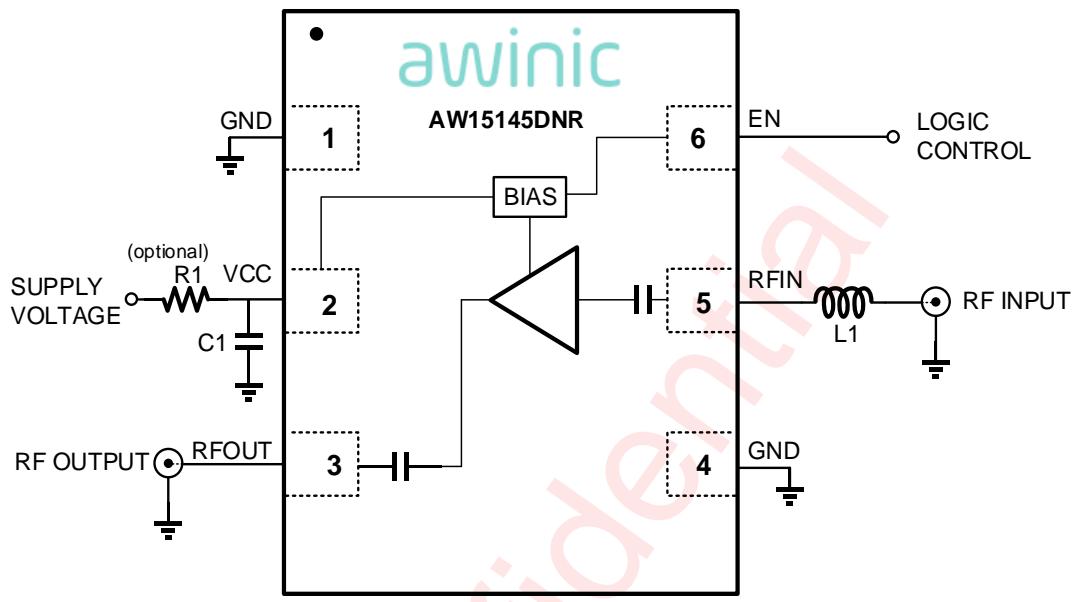


L1, C1, R1 Closed to LNA

**Figure 1(a)    Typical Application Circuit of AW15145DNR for GPS L1**
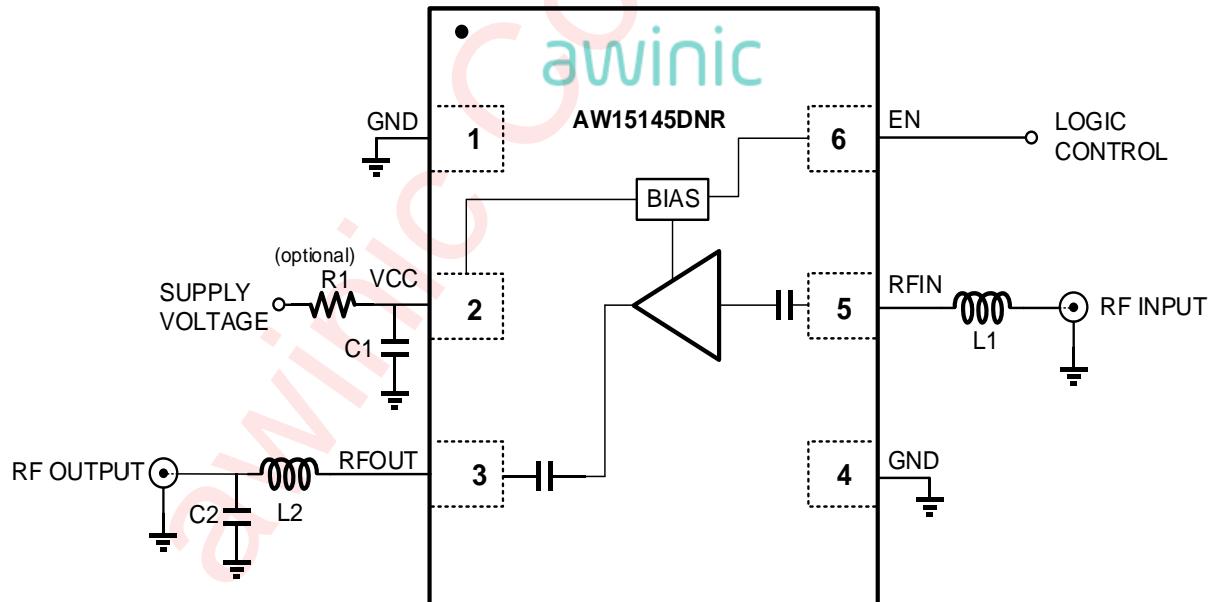


L1, L2, C1, C2, R1 Closed to LNA

**Figure 1(b)    Typical Application Circuit of AW15145DNR for GPS L5**

# RECOMMENDED COMPONENTS LIST

Table1 and talble2 list the recommended inductor types and values; Table 3 lists the recommended capacitor types and values.

Table1: list of inductor for GPS L1

| Component | Part Number | Inductance | Q(min) | Q Test Frequency | Supplier | Size |
|---|---|---|---|---|---|---|
| | Units | nH | | MHz | | |
| L1 | LQW15A | 10 | 25 | 250 | Murata | 0402 |
| L1 | SDWL1005C | 10 | 24 | 250 | Sunlord | 0402 |

Table2: list of inductor for GPS L5

| Component | Part Number | Inductance | Q(min) | Q Test Frequency | Supplier | Size |
|---|---|---|---|---|---|---|
| | Units | nH | | MHz | | |
| L1 | LQW15A | 18 | 25 | 250 | Murata | 0402 |
| L2 | LQW15A | 9.1 | 25 | 250 | Murata | 0402 |

Table2: list of capacitor

| Component | Part Number | Capacitance | Rated Voltage | Supplier | Size |
|---|---|---|---|---|---|
| | Units | pF | V | | |
| C1 | GRM155 | 1000 | 50 | Murata | 0402 |
| C2 | GRM155 | 1.5 | 50 | Murata | 0402 |

# PIN CONFIGURATION AND TOP MARK



AW15145DNR
(Top View)

GND  1     6  EN

VCC  2     5  RFIN

RFOUT  3     4  GND
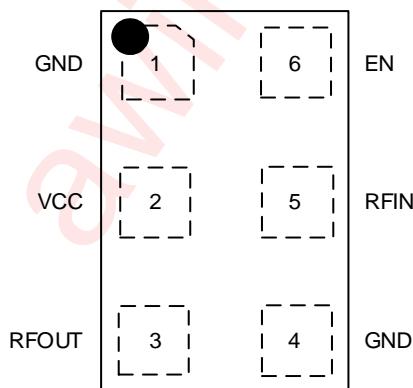
AW15145DNR Marking
(Top View)

5X
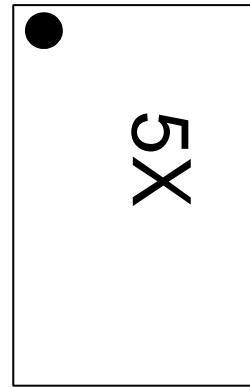
5 – AW15145DNR

X – Production Tracing Code

**Figure 2        Pin Configuration and Top Mark**

## PIN DEFINITION

| No. | NAME | DESCRIPTION |
|-----|------|-------------|
| 1 | GND | Ground |
| 2 | VCC | DC Supply |
| 3 | RFOUT | LNA output |
| 4 | GND | Ground |
| 5 | RFIN | LNA input |
| 6 | EN | Logic control |

## FUNCTIONAL BLOCK DIAGRAM
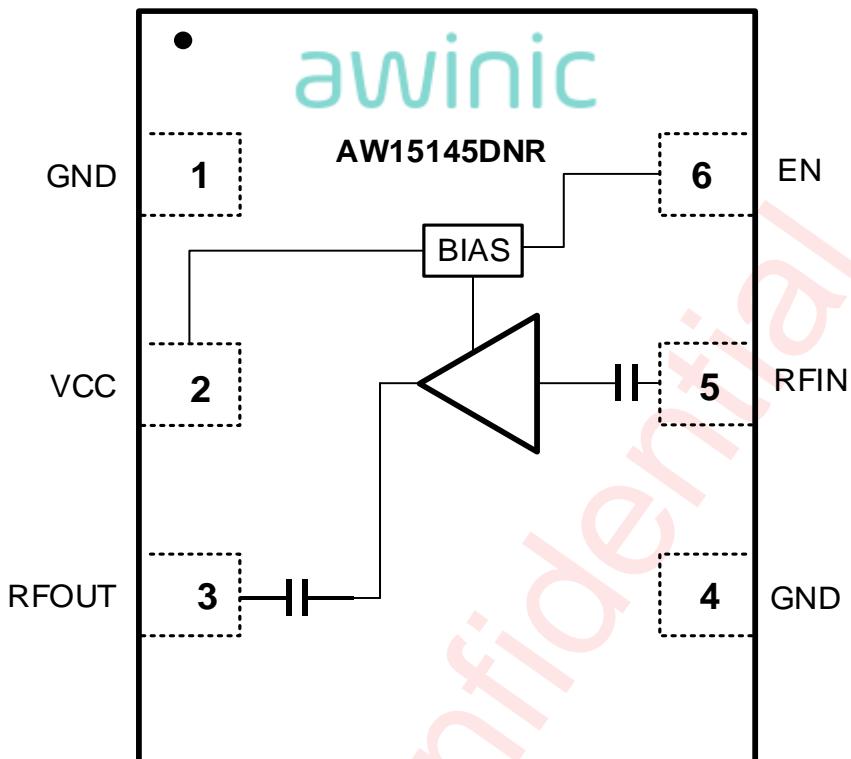


**Figure 3    Functional Block Diagram**

## ORDERING INFORMATION

| Part Number | Temperature | Package | Marking | Moisture Sensitivity Level | Environmental Information | Delivery Form |
|---|---|---|---|---|---|---|
| AW15145DNR | -40°C ~ 85°C | DFN 1.1mmx0.7mm-6L | 5 | MSL1 | ROHS+HF | 9000 units/ Tape and Reel |

## ABSOLUTE MAXIMUM RATINGS[1]

| PARAMETERS | Symbol | Min. | Typ. | Max. | |
|---|---|---|---|---|---|
| Supply Voltage at pin VCC | $V_{CC}$ | -0.3 | - | 3.6 | V |
| Voltage at pin EN [2] | $V_{EN}$ | -0.3 | - | 3.6 | V |
| Current into pin VCC | $I_{CC}$ | - | - | 30 | mA |
| RF input power [3] | $P_{IN}$ | - | - | 10 | dBm |
| Package thermal resistance | $\theta_{JA}$ | - | 148 | - | ℃/W |
| Junction temperature | $T_J$ | - | - | 150 | ℃ |
| Storage temperature range | $T_{STG}$ | -65 | - | 150 | ℃ |
| Ambient temperature range | $T_{amb}$ | -40 | - | 85 | ℃ |
| Solder temperature(10s) | | - | 260 | - | ℃ |
| ESD range | | | | | |
| HBM [4] | | | ±3000 | | V |
| CDM [4] | | | ±2000 | | V |
| Latch-up | | | | | |
| Test condition: JESD78E | | | +IT: +200 | | mA |
| | | | -IT: -200 | | mA |

*Note1: Stresses beyond those listed under "absolute maximum ratings" Nov cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum rated conditions for extended periods Nov affect device reliability.*

*Note2: Warning: due to internal ESD diode protection, the applied DC voltage should not exceed 3.6V in order to avoid excess current.*

*Note3: The RF input and RF output are AC coupled through internal DC blocking capacitor.*

*Note4: HBM standard: ESDA/JEDEC JS-001. CDM standard: ESDA/JEDEC JS-002.*

# ELECTRICAL CHARACTERISTICS

(AW15145DNR EVB[1]; Typical values are at VCC=$V_{EN}$=2.8V and TA=+25°C, f=1575.42MHz, unless otherwise noted)

| PARAMETER | | TEST CONDITION | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|
| **DC ELECTRICAL CHARACTERISTICS** | | | | | | |
| $V_{CC}$ | Supply Voltage | | 1.5 | - | 3.3 | V |
| $I_{SD}$ | Shut-Down Current | EN=Low | | | 2 | µA |
| $I_{CC}$ | Supply Current | EN=High | | 7.8 | 12 | mA |
| $V_{EN}$ | Digital Input-Logic High | | 1.0 | | 3.3 | V |
| $V_{EN}$ | Digital Input-Logic Low | | | | 0.3 | V |
| **AC ELECTRICAL CHARACTERISTICS** | | | | | | |
| Gp | Power Gain | | 17.5 | 19 | 20.5 | dB |
| $RL_{in}$ | Input Return Loss | | 8 | 10 | | dB |
| $RL_{out}$ | Output Return Loss | | 10 | 16 | | dB |
| ISL | Reverse Isolation | | 20 | 27 | | dB |
| NF | Noise Figure[2] | Zs=50 ohm; No jammer | | 0.75 | 1.2 | dB |
| Kf | Stability factor | f=20MHz…10GHz | 1 | | | |
| IP1dB | Inband input 1dB-compression point | f=1575.42MHz | -12 | -10.5 | | dBm |
| $IIP3_{ib}$ | Inband input 3$^{rd}$-order intercept point | f1=1574.42MHz; f2=1575.42MHz; Pin=-25dBm; | -5 | -2 | | dBm |
| $IIP3_{oob}$ | Out-of-band input 3$^{rd}$-order intercept point[3] | f1=1713MHz; f2=1851MHz; Pin_f1=-20dBm; Pin_f2=-65dBm; | -3 | -1 | | dBm |
| IMD3 | 3$^{rd}$-order intermodulation distoration | f1=1713MHz; f2=1851MHz; Pin_f1=-20dBm; Pin_f2=-65dBm; | | -83 | | dBm |
| $t_{on}$ | turn-on time | time from $V_{EN}$ ON to 90% of the final gain | | | 2 | µs |
| $t_{off}$ | turn-off time | time from $V_{EN}$ OFF to 10% of the gain | | | 1 | µs |

*Note1*: *input matched to 50 ohm using a high quality-factor 10nH inductor.*

*Note2*: *PCB losses are subtracted.*

*Note3*: *IP3=P1+(P2+Gain$_{1575MHZ}$-IM3)/2*

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(AW15145DNR EVB[1]; Typical values are at VCC=$V_{EN}$=1.8V and TA=+25°C, f=1575.42MHz, unless otherwise noted)

| PARAMETER | | TEST CONDITION | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|
| **DC ELECTRICAL CHARACTERISTICS** | | | | | | |
| $V_{CC}$ | Supply Voltage | | 1.5 | - | 3.3 | V |
| $I_{SD}$ | Shut-Down Current | EN=Low | | | 2 | µA |
| $I_{CC}$ | Supply Current | EN=High | | 6.7 | 10 | mA |
| $V_{EN}$ | Digital Input-Logic High | | 1.0 | | 3.3 | V |
| $V_{EN}$ | Digital Input-Logic Low | | | | 0.3 | V |
| **AC ELECTRICAL CHARACTERISTICS** | | | | | | |
| Gp | Power Gain | | 17 | 18.5 | 20 | dB |
| $RL_{in}$ | Input Return Loss | | 8 | 9.5 | | dB |
| $RL_{out}$ | Output Return Loss | | 10 | 16 | | dB |
| ISL | Reverse Isolation | | 20 | 27 | | dB |
| NF | Noise Figure[2] | Zs=50 ohm; No jammer | | 0.78 | 1.2 | dB |
| Kf | Stability factor | f=20MHz…10GHz | 1 | | | |
| IP1dB | Inband input 1dB-compression point | f=1575.42MHz | -14 | -12.5 | | dBm |
| $IIP3_{ib}$ | Inband input 3rd-order intercept point | f1=1574.42MHz; f2=1575.42MHz; Pin=-25dBm; | -5.5 | -3.5 | | dBm |
| $IIP3_{oob}$ | Out-of-band input 3rd-order intercept point[3] | f1=1713MHz; f2=1851MHz; Pin_f1=-20dBm; Pin_f2=-65dBm; | -5 | -3 | | dBm |
| IMD3 | 3rd-order intermodulation distoration | f1=1713MHz; f2=1851MHz; Pin_f1=-20dBm; Pin_f2=-65dBm; | | -80 | | dBm |
| $t_{on}$ | turn-on time | time from $V_{EN}$ ON to 90% of the final gain | | | 2 | µs |
| $t_{off}$ | turn-off time | time from $V_{EN}$ OFF to 10% of the gain | | | 1 | µs |

*Note1:* *input matched to 50 ohm using a high quality-factor 10nH inductor.*

*Note2:* *PCB losses are subtracted.*

*Note3:* *IP3=P1+(P2+Gain$_{1575MHZ}$-IM3)/2.*

(AW15145DNR EVB[1]; Typical values are at VCC=$V_{EN}$=2.8V and TA=+25°C, f=1176.45MHz, unless otherwise noted)

| PARAMETER | | TEST CONDITION | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|
| **DC ELECTRICAL CHARACTERISTICS** | | | | | | |
| $V_{CC}$ | Supply Voltage | | 1.5 | - | 3.3 | V |
| $I_{SD}$ | Shut-Down Current | EN=Low | | | 2 | µA |
| $I_{CC}$ | Supply Current | EN=High | | 7.8 | 12 | mA |
| $V_{EN}$ | Digital Input-Logic High | | 1.0 | | 3.3 | V |
| $V_{EN}$ | Digital Input-Logic Low | | | | 0.3 | V |
| **AC ELECTRICAL CHARACTERISTICS** | | | | | | |
| Gp | Power Gain | | 17.5 | 18.6 | 20 | dB |
| $RL_{in}$ | Input Return Loss | | 7 | 9 | | dB |
| $RL_{out}$ | Output Return Loss | | 10 | 18 | | dB |
| ISL | Reverse Isolation | | 20 | 29.5 | | dB |
| NF | Noise Figure[2] | Zs=50 ohm; No jammer | | 0.78 | 1.2 | dB |
| Kf | Stability factor | f=20MHz…10GHz | 1 | | | |
| IP1dB | Inband input 1dB-compression point | f=1176.45MHz | -15 | -13.1 | | dBm |
| IIP3$_{ib}$ | Inband input 3rd-order intercept point | f1=1176.45MHz; f2=1177.45MHz; Pin=-30dBm; | -5.6 | -3.6 | | dBm |
| IIP3$_{oob}$ | Out-of-band input 3rd-order intercept point[3] | f1=1800MHz; f2=2400MHz; Pin_f1=-30dBm; | -9 | -7.3 | | dBm |
| ton | turn-on time | time from VEN ON to 90% of the final gain | | | 2 | µs |
| toff | turn-off time | time from VEN OFF to 10% of the gain | | | 1 | µs |

**Note1**: *input matched to 50 ohm using a high quality-factor 18nH inductor. Output matching using 9.1nH inductor and 1.5pF capacitor.*

**Note2**: *PCB losses are subtracted.*

(AW15145DNR EVB[1]; Typical values are at VCC=$V_{EN}$=1.8V and TA=+25°C, f=1176.45MHz, unless otherwise noted)

| PARAMETER | | TEST CONDITION | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|
| **DC ELECTRICAL CHARACTERISTICS** | | | | | | |
| $V_{CC}$ | Supply Voltage | | 1.5 | - | 3.3 | V |
| $I_{SD}$ | Shut-Down Current | EN=Low | | | 2 | µA |
| $I_{CC}$ | Supply Current | EN=High | | 6.7 | 10 | mA |
| $V_{EN}$ | Digital Input-Logic High | | 1.0 | | 3.3 | V |
| $V_{EN}$ | Digital Input-Logic Low | | | | 0.3 | V |
| **AC ELECTRICAL CHARACTERISTICS** | | | | | | |
| Gp | Power Gain | | 17 | 17.8 | 20 | dB |
| $RL_{in}$ | Input Return Loss | | 6.5 | 8.5 | | dB |
| $RL_{out}$ | Output Return Loss | | 10 | 18 | | dB |
| ISL | Reverse Isolation | | 20 | 29 | | dB |
| NF | Noise Figure[2] | Zs=50 ohm; No jammer | | 0.82 | 1.2 | dB |
| Kf | Stability factor | f=20MHz…10GHz | 1 | | | |
| IP1dB | Inband input 1dB-compression point | f=1176.45MHz | -16 | -14.3 | | dBm |
| IIP3$_{ib}$ | Inband input 3rd-order intercept point | f1=1176.45MHz; f2=1177.45MHz; Pin=-30dBm; | -7.2 | -5.2 | | dBm |
| IIP3$_{oob}$ | Out-of-band input 3rd-order intercept point[3] | f1=1800MHz; f2=2400MHz; Pin_f1=-30dBm; | -11 | -9 | | dBm |
| ton | turn-on time | time from VEN ON to 90% of the final gain | | | 2 | µs |
| toff | turn-off time | time from VEN OFF to 10% of the gain | | | 1 | µs |

***Note1**: input matched to 50 ohm using a high quality‑factor 18nH inductor. Output matching using 9.1nH inductor and 1.5pF capacitor.*

***Note2**: PCB losses are subtracted.*

## TEST CIRCUITS

### DC Characteristics

The following is the test bench for power supply, pin voltage, supply current, standby current
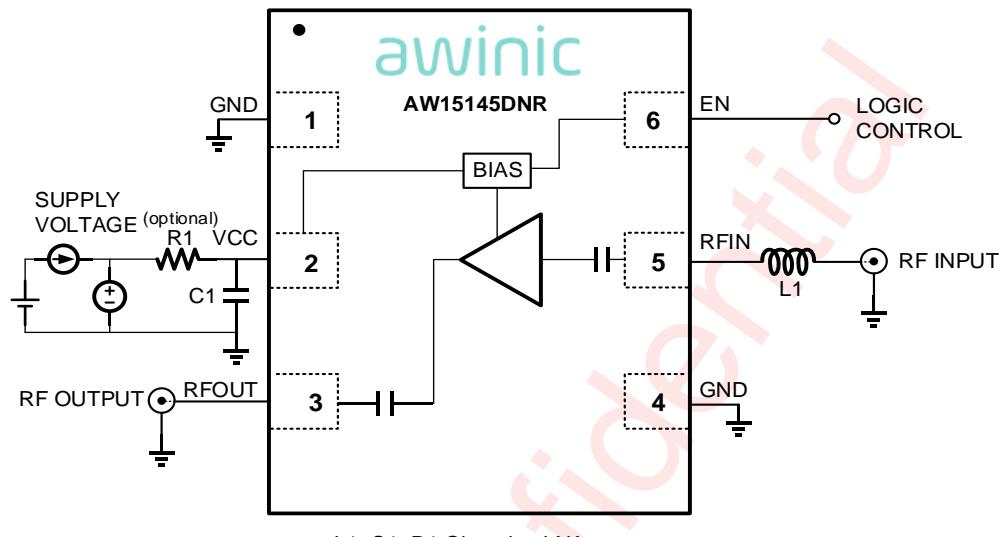


**Figure 4    Test Circuits**

### S Parameter

The following is the test bench for input return loss, output return loss, reverse isolation, forward gain, and 1dB gain compression.
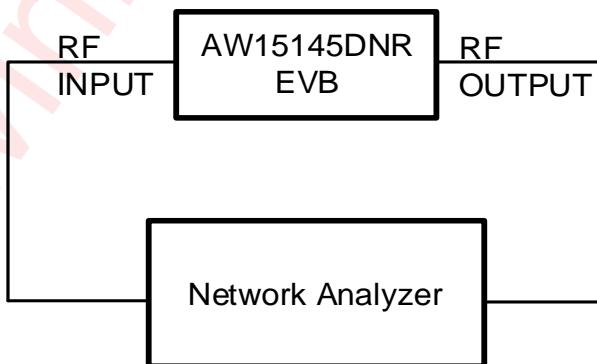


**Figure 5    S Parameter Test Bench**

## Noise Figure

The following is the test bench for noise figure, power gain.
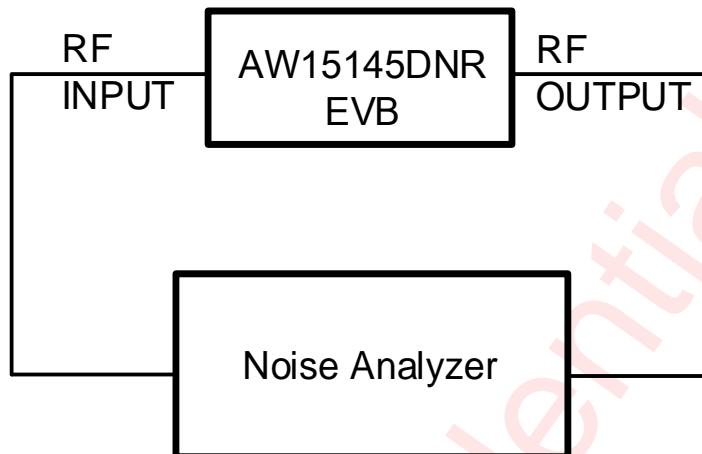
**Figure 6    Noise Figure Test Bench**

## Intermodulation distortion

The following is the test bench for third-order intercept point and second-order intercept point.

**Figure 7    IIP3 Test Bench**

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## Package Description

Pin1 Corner

0.70±0.05

1.10±0.05

TOP VIEW

0.37±0.03

0.10 REF

0 ~ 0.05

SIDE VIEW

6X(0.20±0.05)

6X0.05 REF

6X(0.20±0.05)

4X0.40 TYP

3    4

SYMM ₵

0.10 REF

1    6

4X0.05 REF

6X0.10 REF

SYMM ₵
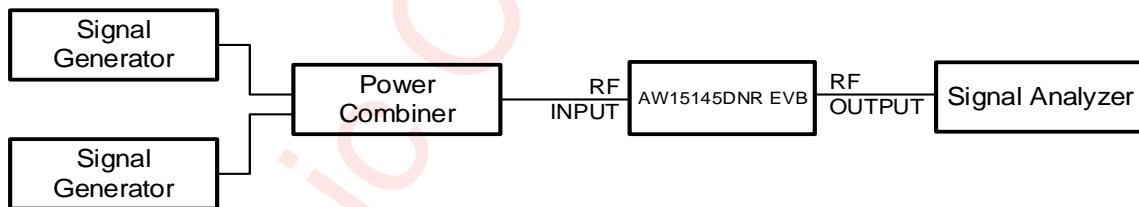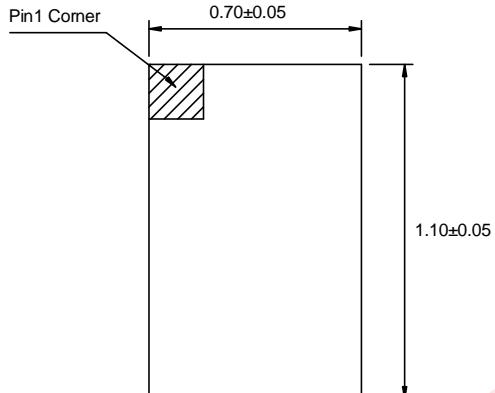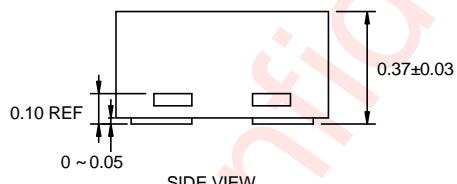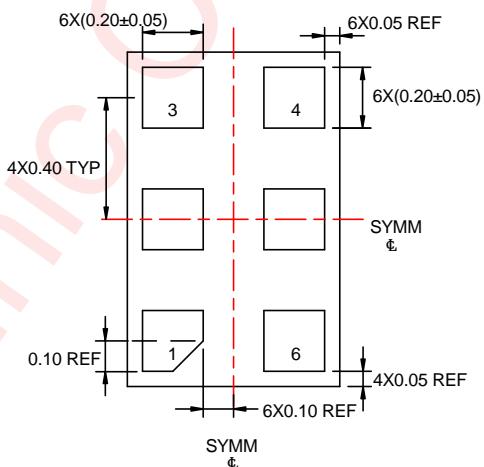
BOTTOM VIEW

Unit : mm

**Package Outline**

## LAND PATTERN

0.80 REF

1

6

4X0.40 TYP

SYMM
₵

1.00 REF

6X0.20 TYP

3

4

SYMM
₵

6X0.30 TYP

0.05 MAX
All AROUND

METAL

SOLDER MASK
OPENING

NON-SOLDER MASK DEFINED

0.05 MIN
ALL AROUND

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

SOLDER MASK DEFINED

Unit: mm
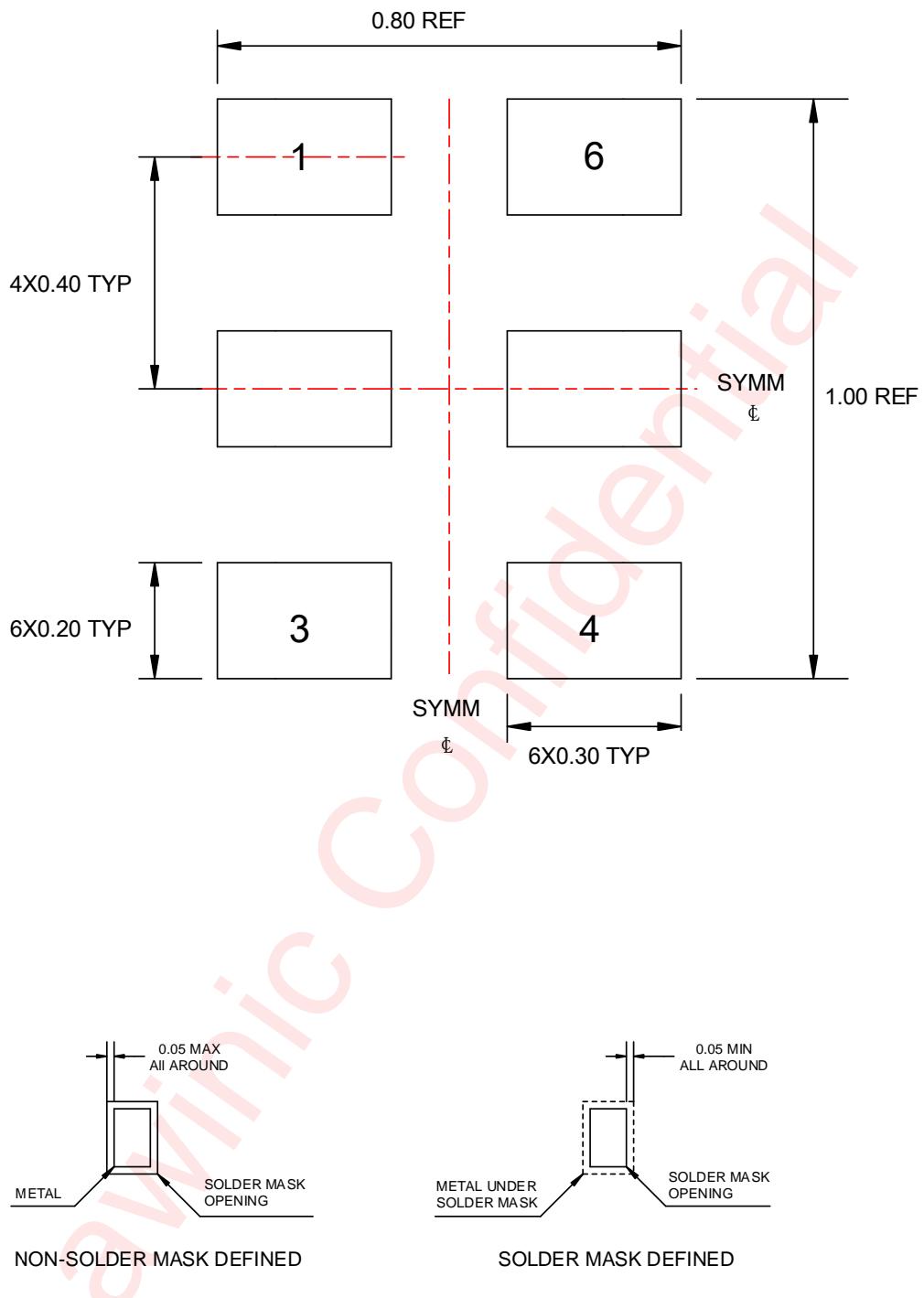
**Figure 9　Land Pattern**

## TAPE & REEL DESCRIPTION

REEL DIMENSIONS

TAPE DIMENSIONS

A0：Dimension designed to accommodate the component width
B0：Dimension designed to accommodate the component length
K0：Dimension designed to accommodate the component thickness
W：Overall width of the carrier tape
P0：Pitch between successive cavity centers and sprocket hole
P1：Pitch between successive cavity centers
P2：Pitch between sprocket hole
D1：Reel Diameter
D0：Reel Width

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Pin 1

Sprocket Holes

User Direction of Feed

Pocket Quadrants
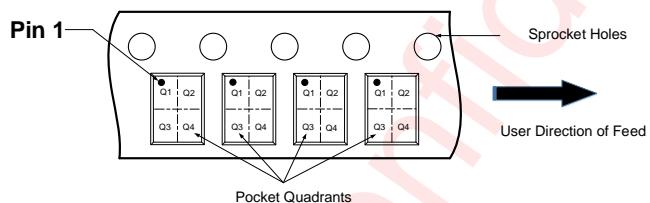
DIMENSIONS AND PIN1 ORIENTATION

| D1 (mm) | D0 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P0 (mm) | P1 (mm) | P2 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|
| 178 | 8.4 | 0.82 | 1.22 | 0.46 | 2 | 2 | 4 | 8 | Q1 |

All dimensions are nominal

**Figure 10    Tape & Reel Description**

## REVISION HISTORY

| Version | Date | Change Record |
|---------|------|---------------|
| V1.0 | Nov. 2020 | Officially Released |
| V1.1 | Nov. 2020 | Added P1dB/ $IIP3_{ib}$ / $IIP3_{oob}$ OF L5 BAND |

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